

BUL742C BULB742C

High voltage fast-switching NPN power transistor

Features

- Low spread of dynamic parameters
- High voltage capability
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

- Electronic ballast for fluorescent lighting
- Switch mode power supplies

Description

The devices are manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability. Thanks to an increased intermediate layer, it has an intrinsic ruggedness which enables the transistor to withstand an high collector current level during breakdown condition, without using the transil protection usually necessary in typical converters for lamp ballast.

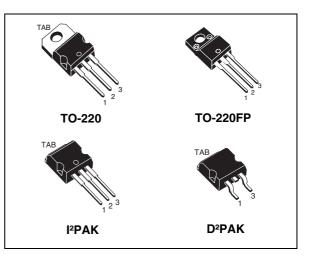


Figure 1. Internal schematic diagram

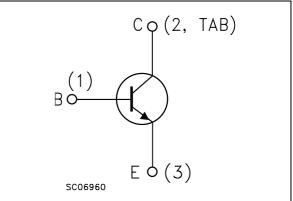


Table 1. Device summary

Order codes	Markings	Packages	Packaging
BUL742C	BUL742C	TO-220	
BUL742CFP	BUL742CFP	TO-220FP	Tube
BULB742C-1	BULB742C	I²PAK	
BULB742CT4	BULB742C	D²PAK	Tape and reel

November 2010

1 Electrical ratings

Table 2. Absolute maximum ratings	Table 2.	Absolute	maximum	ratings
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Symbol	Parameter TO-220 / D ² PAK / I ² PAK TO-220FP		Unit	
V _{CES}	Collector-emitter voltage (V _{BE} = 0) 1050			
V _{CEO}	Collector-emitter voltage $(I_B = 0)$	400)	V
V _{EBO}	Emitter-base voltage ($I_c = 0$, $I_B = 2$ A, $t_p < 10$ ms)	V _(BR)	EBO	V
Ι _C	Collector current 4		А	
I _{CM}	Collector peak current (t _P < 5 ms) 8		А	
Ι _Β	Base current 2		А	
I _{BM}	Base peak current (t _P < 5 ms)4		А	
P _{TOT}	Total dissipation at $T_c = 25 \text{ °C}$ 70 30		W	
T _{STG}	Storage temperature -65 to 150		°C	
V _{ISO}	Isolation withstand voltage (RMS) from all three 1500		V	
TJ	Max. operating junction temperature	150)	°C

Table 3. Thermal data

Symbol	Parameter	TO-220/D ² PAK/I ² PAK	TO-220FP	Unit
R _{thJC}	Thermal resistance junction - case	1.79	4.17	°C/W
R _{thJA}	Thermal resistance junction - ambient	62.5	62.5	°C/W



2 Electrical characteristics

 $T_{case} = 25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 1050 V		0.2	10	μA
I _{CEO}	Collector cut-off current $(I_B = 0)$	V _{CE} = 400 V		10	250	μA
V _{(BR)EBO}	Emitter base breakdown voltage (I _C = 0)	I _E = 1 mA	15	19	24	V
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 10 mA	400	450		v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_{C} = 1 A$ $I_{B} = 0.2 A$ $I_{C} = 3.5 A$ $I_{B} = 1 A$		0.15 0.6	0.5 1.5	V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 3.5 A I _B = 1 A		1.1	1.5	V
$h_{FE}^{(1)}$	DC current gain			75 35	100 50	
t _s t _f	Resistive load Storage time Fall time	$\begin{split} I_{C} &= 2 \text{ A} & V_{CC} &= 125 \text{ V} \\ I_{B1} &= -I_{B2} &= 400 \text{ mA} \\ t_{p} &= 300 \mu \text{s} \text{V}_{BE(off)} &= -5 \text{ V} \end{split}$		2.4 350	3.5 500	µs ns
E _{ar}	Repetitive avalanche energy	L = 2 mH C = 1.8 nF $V_{BE(off)}$ = -5 V	6			mJ

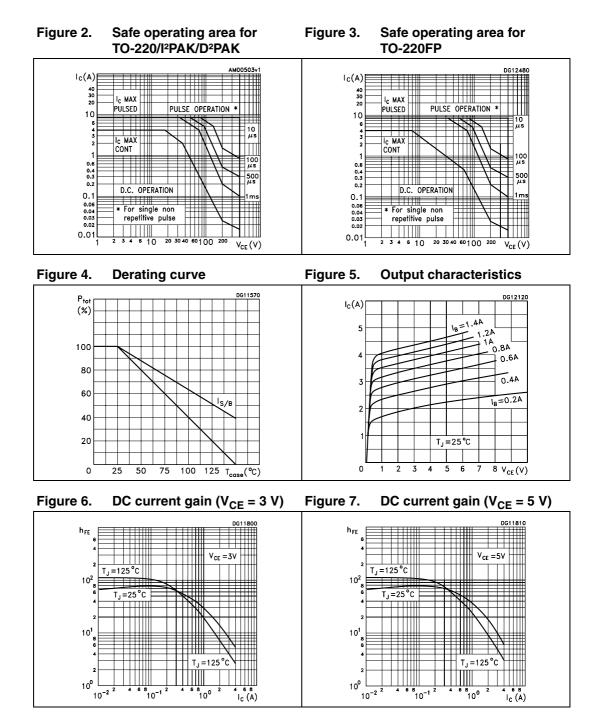
Table 4. Electrical characteristics

1. Pulse test: pulse duration \leq 300 µs, duty cycle \leq 2 %.



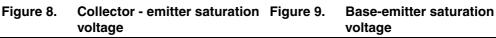
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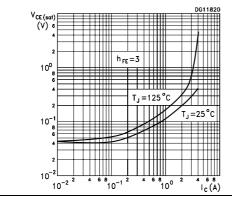
2.1 Electrical characteristics (curves)

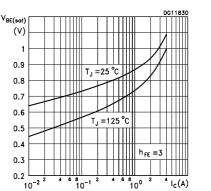


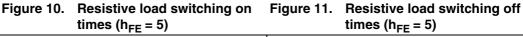


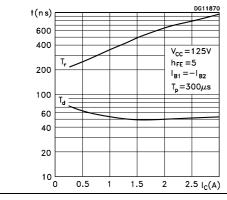
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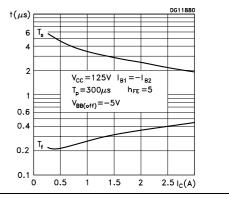
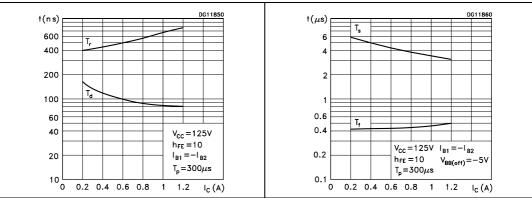


Figure 12. Resistive load switching on times ($h_{FE} = 10$)

Figure 13. Resistive load switching off times ($h_{FE} = 10$)



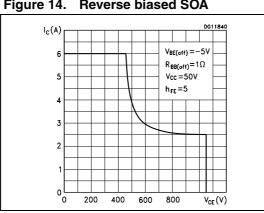
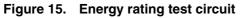


Figure 14. Reverse biased SOA



3 Test circuit



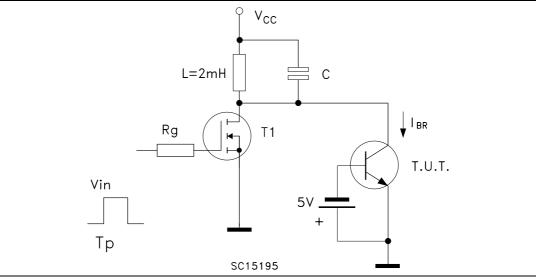
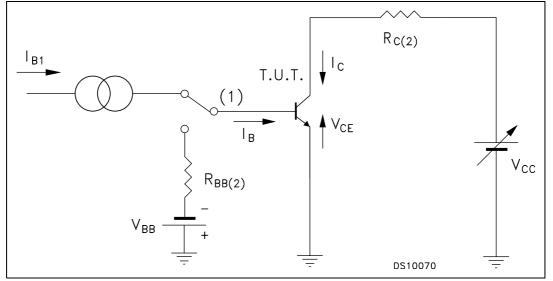


Figure 16. Resistive load switching test circuit





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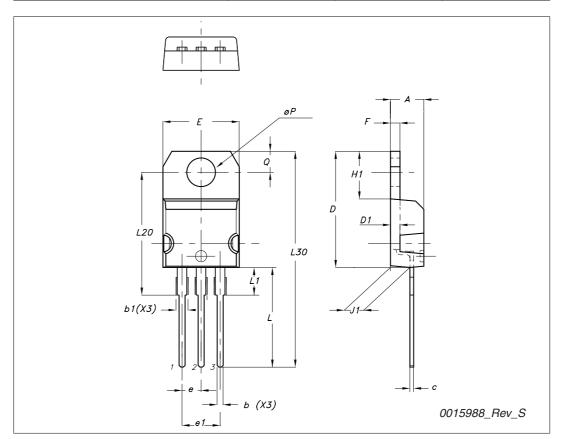
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.



Dim	mm		
DIM	Min	Тур	Max
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
С	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95

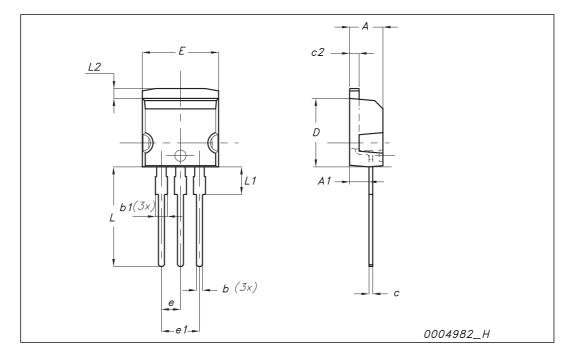






I²PAK (TO-262) mechanical data

Dim		mm		inch		
Dim	Min	Тур	Max	Min	Тур	Max
A	4.40		4.60	0.173		0.181
A1	2.40		2.72	0.094		0.107
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
С	0.49		0.70	0.019		0.027
c2	1.23		1.32	0.048		0.052
D	8.95		9.35	0.352		0.368
е	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
E	10		10.40	0.393		0.410
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L2	1.27		1.40	0.050		0.055

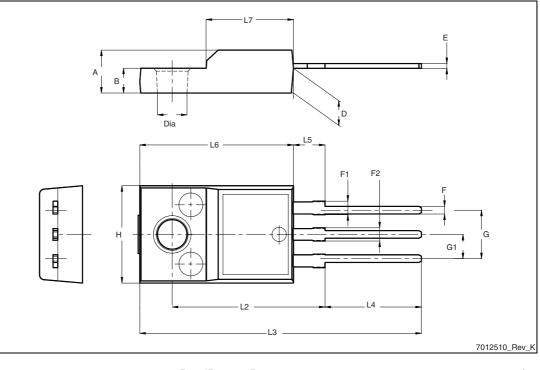




Dim		mm.				
Dim.	Min.	Тур.	Max.			
А	4.4		4.6			
В	2.5		2.7			
D	2.5		2.75			
E	0.45		0.7			
F	0.75		1			
F1	1.15		1.70			
F2	1.15		1.70			
G	4.95		5.2			
G1	2.4		2.7			
Н	10		10.4			
L2		16				
L3	28.6		30.6			
L4	9.8		10.6			
L5	2.9		3.6			
L6	15.9		16.4			
L7	9		9.3			
Dia	3		3.2			

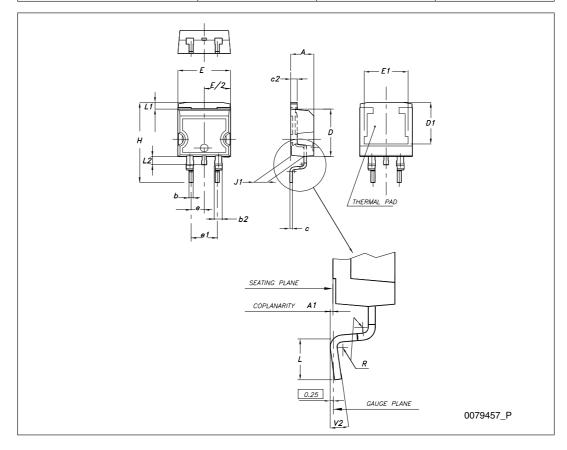
Table 5.TO-220FP mechanical data

Figure 17. TO-220FP drawing





D ² PAK (TO-263) mechanical data				
Dim.		mm.		
Dini.	Min.	Тур.	Max.	
A	4.40		4.60	
A1	0.03		0.23	
b	0.70		0.93	
b2	1.14		1.70	
с	0.45		0.60	
c2	1.23		1.36	
D	8.95		9.35	
D1	7.50			
E	10		10.40	
E1	8.50			
е		2.54		
e1	4.88		5.28	
Н	15		15.85	
J1	2.49		2.69	
L	2.29		2.79	
L1	1.27		1.40	
L2	1.30		1.75	
R		0.4		
V2	0°		8°	





5 Revision history

Table 6.Document revision history

Date	Revision	Changes
21-Jun-2004	1	First release
10-Aug-2007	2	No content changes, document reformatted
27-May-2008	3	Added I ² PAK package
30-Nov-2010	4	Added TO-220FP and D ² PAK packages



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